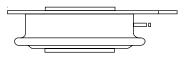


Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 410 A



410 A

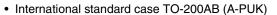
TO-200AB (A-PUK)

PRODUCT SUMMARY

 $I_{T(AV)}$

FEATURES

- · Center amplifying gate
- Metal case with ceramic insulator





• Designed and qualified for industrial level



TYPICAL APPLICATIONS

- · DC motor controls
- · Controlled DC power supplies
- AC controllers

PARAMETER	TEST CONDITIONS	VALUES	UNITS	
1		410	А	
I _{T(AV)}	T _{hs}	55	°C	
1		780	Α	
I _{T(RMS)}	T _{hs}	25	°C	
1	50 Hz	5700	^	
I _{TSM}	60 Hz	5970	A	
l ² t	50 Hz	163	kA ² s	
1-1	60 Hz	149	KA-S	
V _{DRM} /V _{RRM}		400 to 2000	V	
t _q	Typical	100	μs	
T _J		- 40 to 125	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VDRM/VRRM, MAXIMUM REPETITIVE PEAK AND CODE OFF-STATE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA				
	04	400	500					
	08	800	900					
	12	1200	1300					
ST230CC	14	1400	1500	30				
	16	1600	1700					
	18	1800	1900					
	20	2000	2100					

Document Number: 94398 Revision: 11-Aug-08

ST230CPbF Series

Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 410 A



ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	-	180° conduction, half sine wave double side (single side) cooled		410 (165)	Α	
at heatsink temperature	$I_{T(AV)}$			55 (85)	°C	
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	DC at 25 °C heatsink temperature double side cooled			
		t = 10 ms	No voltage		5700	
Maximum peak, one-cycle		t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	5970	А
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		4800	
		t = 8.3 ms	reapplied		5000	
Mariana 121 factorias	l ² t	t = 10 ms	No voltage reapplied		163	- kA ² s
		t = 8.3 ms			148	
Maximum I ² t for fusing		t = 10 ms			115	
		t = 8.3 ms	reapplied		105	
Maximum I $^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			1630	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$			0.92	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.98	ľ
Low level value of on-state slope resistance	r _{t1}	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$			0.88	0
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.81	mΩ
Maximum on-state voltage	V_{TM}	$I_{pk} = 880 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.69	V
Maximum holding current	I _H	T 05.00 and a south 40 V and that		600	A	
Maximum (typical) latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000 (300)	mA

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dI/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ V _{DRM}	1000	A/µs		
Typical delay time	t _d	Gate current 1 A, $dI_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0			
Typical turn-off time	ical turn-off time $t_{q} \hspace{1cm} I_{TM} = 300 \text{ A, } T_{J} = T_{J} \text{ maximum, dI/dt} = 20 \text{ A/} \\ V_{R} = 50 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s, gate 0 V 100 }\Omega,$		100	μs		

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs			
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	30	mA			

Document Number: 94398 Revision: 11-Aug-08



Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 410 A

TRIGGERING							
PARAMETER	SYMBOL	TE	ET CONDITIONS	VALUES		LINUTO	
PARAMETER	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS		
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum	, t _p ≤ 5 ms	10.0		w	
Maximum average gate power	P _{G(AV)}	T _J = T _J maximum	, f = 50 Hz, d% = 50	2	.0	VV	
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum	, t _p ≤ 5 ms	3	.0	Α	
Maximum peak positive gate voltage	+ V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms		20		V	
Maximum peak negative gate voltage	- V _{GM}			5.0		V	
		T _J = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest	180	-		
DC gate current required to trigger	I _{GT}	T _J = 25 °C		90	150	mA	
		T _J = 125 °C		40	-		
		T _J = - 40 °C		2.9	-		
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V	
		T _J = 125 °C		1.2	-		
DC gate current not to trigger	I _{GD}	$T_J = T_J \text{ maximum}$	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any	1	0	mA	
DC gate voltage not to trigger	V_{GD}	ij – ijillaxiillulli	unit with rated V _{DRM} anode to cathode applied	0	25	V	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating temperature range	TJ		- 40 to 125	ူင		
Maximum storage temperature range	T _{Stg}		- 40 to 150			
Maximum thermal resistance,	В	DC operation single side cooled	0.17			
junction to heatsink	R_{thJ-hs}	DC operation double side cooled	0.08	K/W		
Maximum thermal resistance,	В	DC operation single side cooled	0.033	TV VV		
case to heatsink		DC operation double side cooled	0.017			
Mounting force, ± 10 %			4900	N		
Wodriting force, ± 10 /6			(500)	(kg)		
Approximate weight			50	g		
Case style		See dimensions - link at the end of datasheet	TO-200AB (A	-PUK)		

△R _{thJC} CONDUCTION								
CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	RECTANGULAR	R CONDUCTION	TEST CONDITIONS	LIMITO		
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		UNITS		
180°	0.015	0.017	0.011	0.011				
120°	0.018	0.019	0.019	0.019	$T_J = T_J$ maximum	K/W		
90°	0.024	0.024	0.026	0.026				
60°	0.035	0.035	0.036	0.036				
30°	0.060	0.060	0.060	0.061				

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 410 A



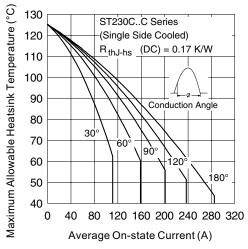


Fig. 1 - Current Ratings Characteristics

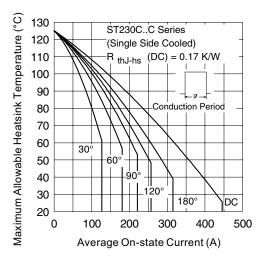


Fig. 2 - Current Ratings Characteristics

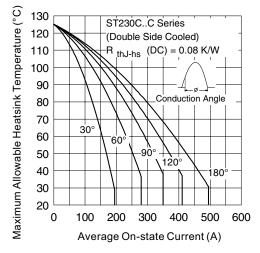


Fig. 3 - Current Ratings Characteristics

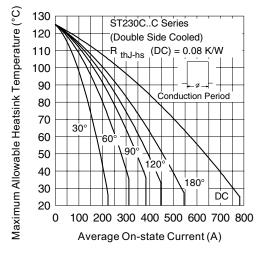


Fig. 4 - Current Ratings Characteristics

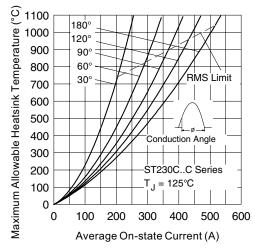


Fig. 5 - On-State Power Loss Characteristics

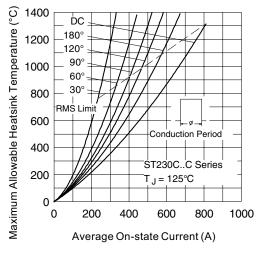


Fig. 6 - On-State Power Loss Characteristics



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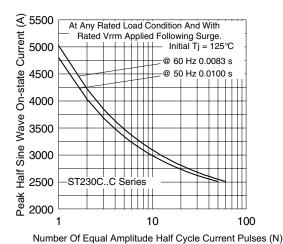


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

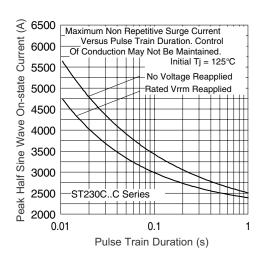


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

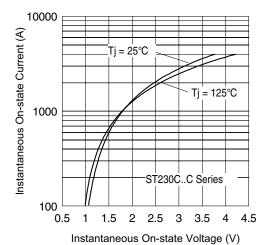


Fig. 9 - On-State Voltage Drop Characteristics

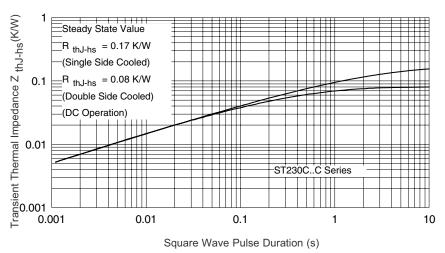


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 410 A



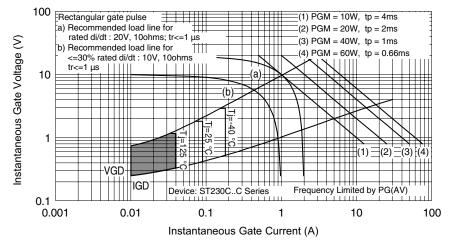
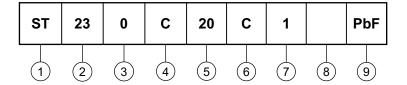


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 Thyristor
- 2 Essential part number
- 3 0 = Converter grade
- 4 C = Ceramic PUK
- 5 Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 6 C = PUK case TO-200AB (A-PUK)
- 7 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)
 - 1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)
 - 2 = Eyelet terminals (gate and auxiliary cathode soldered leads)
 - 3 = Fast-on terminals (gate and auxiliary cathode soldered leads)
- 8 Critical dV/dt: None = 500 V/µs (Standard selection)
 - L = 1000 V/µs (Special selection)
- 9 Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95074			



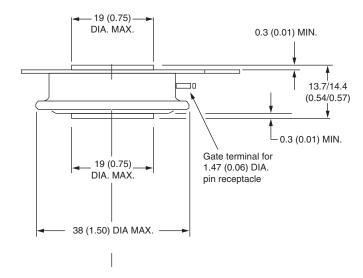
Vishay Semiconductors

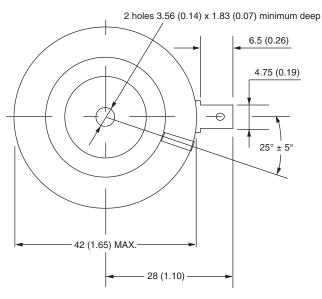
TO-200AB (A-PUK)

DIMENSIONS in millimeters (inches)

Anode to gate

Creepage distance: 7.62 (0.30) minimum Strike distance: 7.12 (0.28) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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